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Details

Product Status	Obsolete
Core Processor	Coldfire V4E
Core Size	32-Bit Single-Core
Speed	166MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I ² C, SPI, UART/USART, USB
Peripherals	DMA, PWM, WDT
Number of I/O	99
Program Memory Size	-
Program Memory Type	ROMless
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.43V ~ 1.58V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	388-BBGA
Supplier Device Package	388-PBGA (27x27)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcf5483czp166

Table 4. DC Electrical Specifications (continued)

Characteristic	Symbol	Min	Max	Units
USB PLL operation voltage range	USB_PLLV _{DD}	1.43	1.58	V
Input high voltage SSTL 3.3V/2.5V ²	V _{IH}	V _{REF} + 0.3	SD V _{DD} + 0.3	V
Input low voltage SSTL 3.3V/2.5V ²	V _{IL}	V _{SS} - 0.3	V _{REF} - 0.3	V
Input high voltage 3.3V I/O pins	V _{IH}	0.7 x EV _{DD}	EV _{DD} + 0.3	V
Input low voltage 3.3V I/O pins	V _{IL}	V _{SS} - 0.3	0.35 x EV _{DD}	V
Output high voltage I _{OH} = 8 mA, 16 mA, 24 mA	V _{OH}	2.4	—	V
Output low voltage I _{OL} = 8 mA, 16 mA, 24 mA ⁵	V _{OL}	—	0.5	V
Capacitance ³ , V _{in} = 0 V, f = 1 MHz	C _{IN}	—	TBD	pF
Input leakage current	I _{in}	-1.0	1.0	μA

¹ IV_{DD} and PLL V_{DD} should be at the same voltage. PLL V_{DD} should have a filtered input. Please see Figure 2 for an example circuit. There are three PLL V_{DD} inputs. A filter circuit should be used on each PLL V_{DD} input.

² This specification is guaranteed by design and is not 100% tested.

³ Capacitance C_{IN} is periodically sampled rather than 100% tested.

4 Hardware Design Considerations

4.1 PLL Power Filtering

To further enhance noise isolation, an external filter is strongly recommended for PLL analog V_{DD} pins. The filter shown in Figure 2 should be connected between the board V_{DD} and the PLL V_{DD} pins. The resistor and capacitors should be placed as close to the dedicated PLL V_{DD} pin as possible.

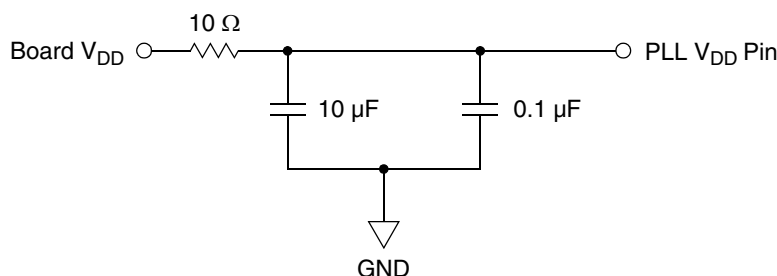
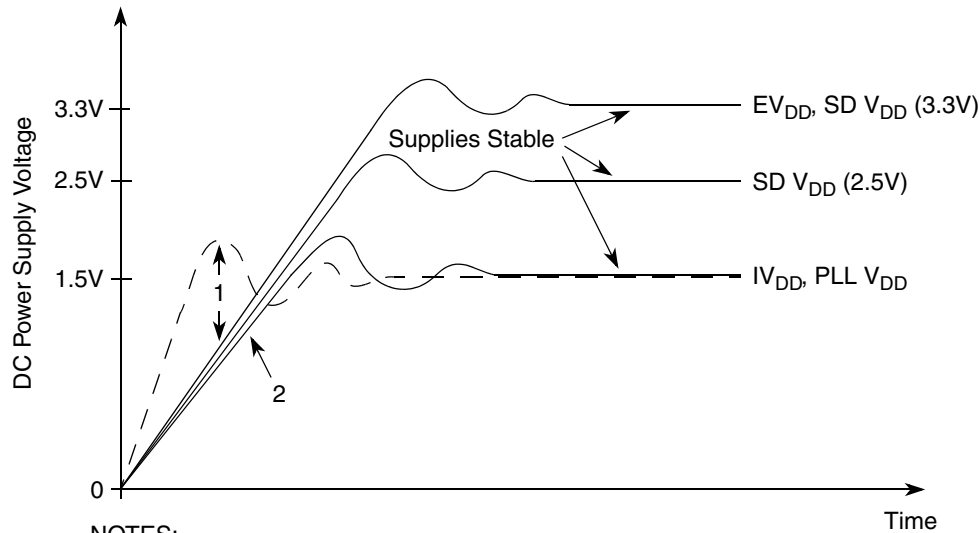


Figure 2. System PLL V_{DD} Power Filter

4.2 Supply Voltage Sequencing and Separation Cautions

Figure 3 shows situations in sequencing the I/O V_{DD} (EV_{DD}), SDRAM V_{DD} (SD V_{DD}), PLL V_{DD} (PLL V_{DD}), and Core V_{DD} (IV_{DD}).



NOTES:

1. IVDD should not exceed EVDD or SD VDD by more than 0.4V at any time, including power-up.
2. Recommended that IVDD/PLL VDD should track EVDD/SD VDD up to 0.9V, then separate for completion of ramps.
3. Input voltage must not be greater than the supply voltage (EVDD, SD VDD, IVDD, or PLL VDD) by more than 0.5V at any time, including during power-up.
4. Use 1 microsecond or slower rise time for all supplies.

Figure 3. Supply Voltage Sequencing and Separation Cautions

The relationship between SD VDD and EVDD is non-critical during power-up and power-down sequences. SD VDD (2.5V or 3.3V) and EVDD are specified relative to IVDD.

4.2.1 Power Up Sequence

If EVDD/SD VDD are powered up with the IVDD at 0V, the sense circuits in the I/O pads cause all pad output drivers connected to the EVDD/SD VDD to be in a high impedance state. There is no limit to how long after EVDD/SD VDD powers up before IVDD must power up. IVDD should not lead the EVDD, SD VDD, or PLL VDD by more than 0.4V during power ramp up or there is high current in the internal ESD protection diodes. The rise times on the power supplies should be slower than 1 microsecond to avoid turning on the internal ESD protection clamp diodes.

The recommended power up sequence is as follows:

1. Use 1 microsecond or slower rise time for all supplies.
2. IVDD/PLL VDD and EVDD/SD VDD should track up to 0.9V, then separate for the completion of ramps with EVDD/SD VDD going to the higher external voltages. One way to accomplish this is to use a low drop-out voltage regulator.

4.2.2 Power Down Sequence

If IVDD/PLL VDD are powered down first, sense circuits in the I/O pads cause all output drivers to be in a high impedance state. There is no limit on how long after IVDD and PLL VDD power down before EVDD or SD VDD must power down. IVDD should not lag EVDD, SD VDD, or PLL VDD going low by more than 0.4V during power down or there is undesired high current in the ESD protection diodes. There are no requirements for the fall times of the power supplies.

The recommended power down sequence is as follows:

1. Drop IVDD/PLL VDD to 0V
2. Drop EVDD/SD VDD supplies

4.4 USB Power Filtering

To minimize noise, an external filter is required for each of the USB power pins. The filter shown in [Figure 6](#) should be connected between the board EV_{DD} or IV_{DD} and each of the USB V_{DD} pins.

- The resistor and capacitors should be placed as close to the dedicated USB V_{DD} pin as possible.
- A separate filter circuit should be included for each USB V_{DD} pin, a total of five circuits.
- All traces should be as low impedance as possible, especially ground pins to the ground plane.
- The filter for USB_PHYVDD to VSS should be connected to the power and ground planes, respectively, not fingers of the planes.
- In addition to keeping the filter components for the USB_PLLVDD as close as practical to the body of the processor as previously mentioned, special care should be taken to avoid coupling switching power supply noise or digital switching noise onto the portion of that supply between the filter and the processor.
- The capacitors for C2 in the table below should be rated X5R or better due to temperature performance.

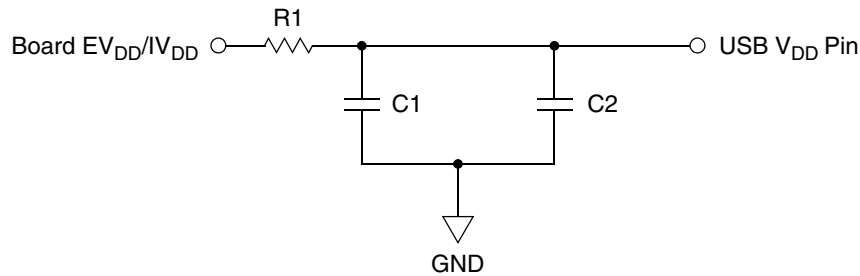


Figure 6. USB V_{DD} Power Filter

NOTE

In addition to the above filter circuitry, a 0.01 F capacitor is also recommended in parallel with those shown.

[Table 5](#) lists the resistor values and supply voltages to be used in the circuit for each of the USB V_{DD} pins.

Table 5. USB Filter Circuit Values

USB V_{DD} Pin	Nominal Voltage	R1 (Ω)	C1 (μ F)	C2 (μ F)
USBVDD (Bias generator supply)	3.3V	10	10	0.1
USB_PHYVDD (Main transceiver supply)	3.3V	0	10	0.1
USB_PLLVDD (PLL supply)	1.5V	10	1	0.1
USB_OSCVDD (Oscillator supply)	3.3V	0	10	0.1
USB_OSCAVDD (Oscillator analog supply)	1.5V	0	10	0.1

4.4.1 Bias Resistor

The USBRBIAS resistor should be placed as close to the dedicated USB 2.0 pins as possible. The tolerance should be $\pm 1\%$.



Figure 7. USBRBIAS Connection

5 Output Driver Capability and Loading

Table 6 lists values for drive capability and output loading.

Table 6. I/O Driver Capability¹

Signal	Drive Capability	Output Load (C_L)
SDRAMC (SDADDR[12:0], SDDATA[31:0], \overline{RAS} , \overline{CAS} , SDDM[3:0], \overline{SDWE} , SDBA[1:0])	24 mA	15 pF
SDRAMC DQS and clocks (SDDQS[3:0], SDRDQS, SDCLK[1:0], \overline{SDCLK} [1:0], SDCKE)	24 mA	15 pF
SDRAMC chip selects (\overline{SDCS} [3:0])	24 mA	15 pF
FlexBus (AD[31:0], \overline{FBCS} [5:0], ALE, $\overline{R/W}$, $\overline{BE/BWE}$ [3:0], \overline{OE})	16 mA	30 pF
FEC (E_n MDIO, E_n MDC, E_n TXEN, E_n TXD[3:0], E_n TXER)	8 mA	15 pF
Timer (TOUT[3:0])	8 mA	50 pF
FlexCAN (CANTX)	8 mA	30 pF
\overline{DACK} [1:0]	8 mA	30 pF
PSC (PSC_n TXD[3:0], $\overline{PSC_nRTS}$ / PSC_n FSYNC,	8 mA	30 pF
DSPI (DSPISOUT, DSPICS0/SS, DSPICS[2:3], DSPICS5/PCSS)	24 mA	50 pF
PCI (PCIAD[31:0], PCIBG[4:1], PCIBG0/PCIREQOUT, PCIDEVSEL, PCICXBE[3:0], PCIFRM, PCIPERR, PCIRESET, PCISERR, PCISTOP, PCIPAR, PCITRDY, PCIIRDY)	16 mA	50 pF
I2C (SCL, SDA)	8 mA	50 pF
BDM (PSTCLK, PSTDDATA[7:0], DSO/TDO,	8 mA	25 pF
RSTO	8 mA	50 pF

¹ The device's pads have balanced sink and source current. The drive capability is the same as the sink capability.

6 PLL Timing Specifications

The specifications in Table 7 are for the CLKIN pin.

Table 7. Clock Timing Specifications

Num	Characteristic	Min	Max	Units
C1	Cycle time	20	40	ns
C2	Rise time (20% of Vdd to 80% of vdd)	—	2	ns
C3	Fall time (80% of Vdd to 20% of Vdd)	—	2	ns
C4	Duty cycle (at 50% of Vdd)	40	60	%

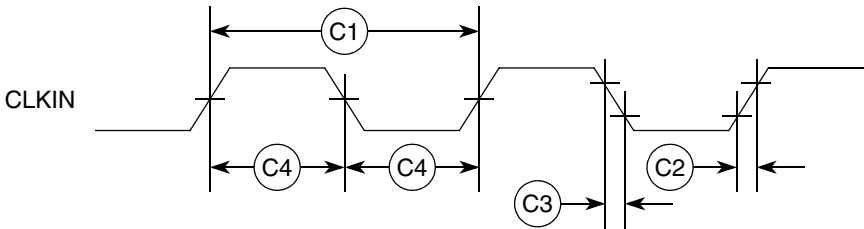


Figure 8. Input Clock Timing Diagram

Table 8 shows the supported PLL encodings.

Table 8. MCF548x Divide Ratio Encodings

AD[12:8] ¹	Clock Ratio	CLKIN—PCI and FlexBus Frequency Range (MHz)	Internal XLB, SDRAM Bus, and PSTCLK Frequency Range (MHz)	Core Frequency Range (MHz)
00011	1:2	41.67–50.0	83.33–100	166.66–200
00101	1:2	25.0–41.67	50.0–83.33 ²	100.0–166.66
01111	1:4	25.0	100	200

¹ All other values of AD[12:8] are reserved.

² DDR memories typically have a minimum speed of 83 MHz. Some vendors specify down to 75 MHz. Check with the memory component specifications to verify.

Figure 9 correlates CLKIN, internal bus, and core clock frequencies for the 1x–4x multipliers.

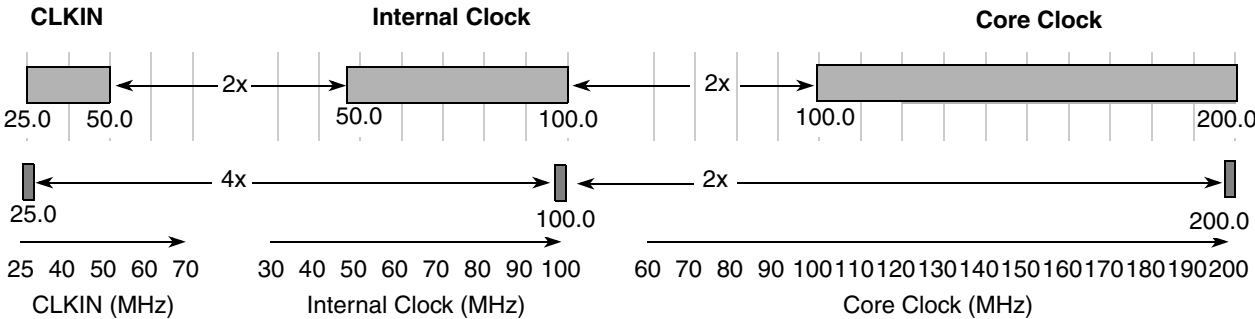


Figure 9. CLKIN, Internal Bus, and Core Clock Ratios

7 Reset Timing Specifications

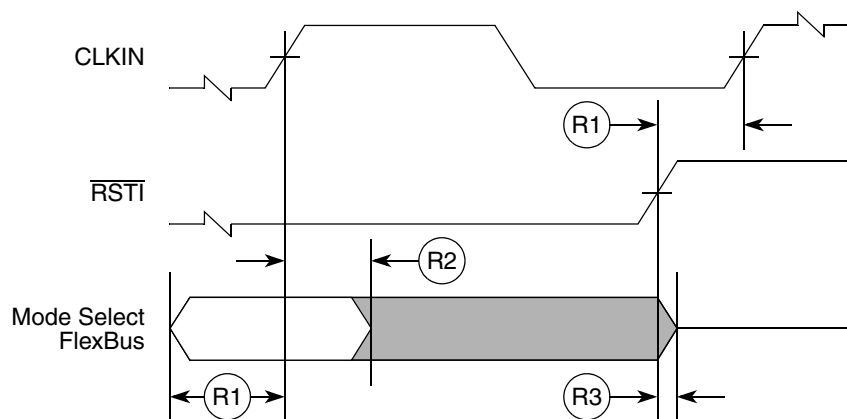
Table 9 lists specifications for the reset timing parameters shown in Figure 10

Table 9. Reset Timing Specifications

Num	Characteristic	50 MHz CLKIN		Units
		Min	Max	
R1 ¹	Valid to CLKIN (setup)	8	—	ns
R2	CLKIN to invalid (hold)	1.0	—	ns
R3	$\overline{\text{RSTI}}$ to invalid (hold)	1.0	—	ns
	$\overline{\text{RSTI}}$ pulse duration	5	—	CLKIN cycles

¹ $\overline{\text{RSTI}}$ and FlexBus data lines are synchronized internally. Setup and hold times must be met only if recognition on a particular clock is required.

Figure 10 shows reset timing for the values in Table 9.



NOTE:

Mode selects are registered on the rising clock edge before the cycle in which $\overline{\text{RSTI}}$ is recognized as being negated.

Figure 10. Reset Timing

8 FlexBus

A multi-function external bus interface called FlexBus is provided on the MCF5482 with basic functionality to interface to slave-only devices up to a maximum bus frequency of 66 MHz. It can be directly connected to asynchronous or synchronous devices such as external boot ROMs, flash memories, gate-array logic, or other simple target (slave) devices with little or no additional circuitry. For asynchronous devices, a simple chip-select based interface can be used. The FlexBus interface has six general purpose chip-selects ($\overline{\text{FBCS}}[5:0]$). Chip-select $\overline{\text{FBCS0}}$ can be dedicated to boot ROM access and can be programmed to be byte (8 bits), word (16 bits), or longword (32 bits) wide. Control signal timing is compatible with common ROM / flash memories.

8.1 FlexBus AC Timing Characteristics

The following timing numbers indicate when data is latched or driven onto the external bus, relative to the system clock.

Table 10. FlexBus AC Timing Specifications

Num	Characteristic	Min	Max	Unit	Notes
	Frequency of Operation	25	50	Mhz	¹
FB1	Clock Period (CLKIN)	20	40	ns	²
FB2	Address, Data, and Control Output Valid (AD[31:0], $\overline{\text{FBCS}}[5:0]$, R/W, ALE, TSIZ[1:0], $\overline{\text{BE}}/\text{BWE}[3:0]$, $\overline{\text{OE}}$, and $\overline{\text{TBST}}$)	—	7.0	ns	³
FB3	Address, Data, and Control Output Hold ((AD[31:0], $\overline{\text{FBCS}}[5:0]$, R/W, ALE, TSIZ[1:0], $\overline{\text{BE}}/\text{BWE}[3:0]$, $\overline{\text{OE}}$, and $\overline{\text{TBST}}$)	1	—	ns	^{3, 4}
FB4	Data Input Setup	3.5	—	ns	
FB5	Data Input Hold	0	—	ns	
FB6	Transfer Acknowledge ($\overline{\text{TA}}$) Input Setup	4	—	ns	
FB7	Transfer Acknowledge ($\overline{\text{TA}}$) Input Hold	0	—	ns	
FB8	Address Output Valid (PCIAD[31:0])	—	7.0	ns	⁵
FB9	Address Output Hold (PCIAD[31:0])	0	—	ns	⁵

¹ The frequency of operation is the same as the PCI frequency of operation. The MCF548X supports a single external reference clock (CLKIN). This signal defines the frequency of operation for FlexBus and PCI.

² Max cycle rate is determined by CLKIN and how the user has the system PLL configured.

³ Timing for chip selects only applies to the $\overline{\text{FBCS}}[5:0]$ signals. Please see [Section 9.2, “DDR SDRAM AC Timing Characteristics”](#) for SDCS[3:0] timing.

⁴ The FlexBus supports programming an extension of the address hold. Please consult the MCF548X specification manual for more information.

⁵ These specs are used when the PCIAD[31:0] signals are configured as 32-bit, non-muxed FlexBus address signals.

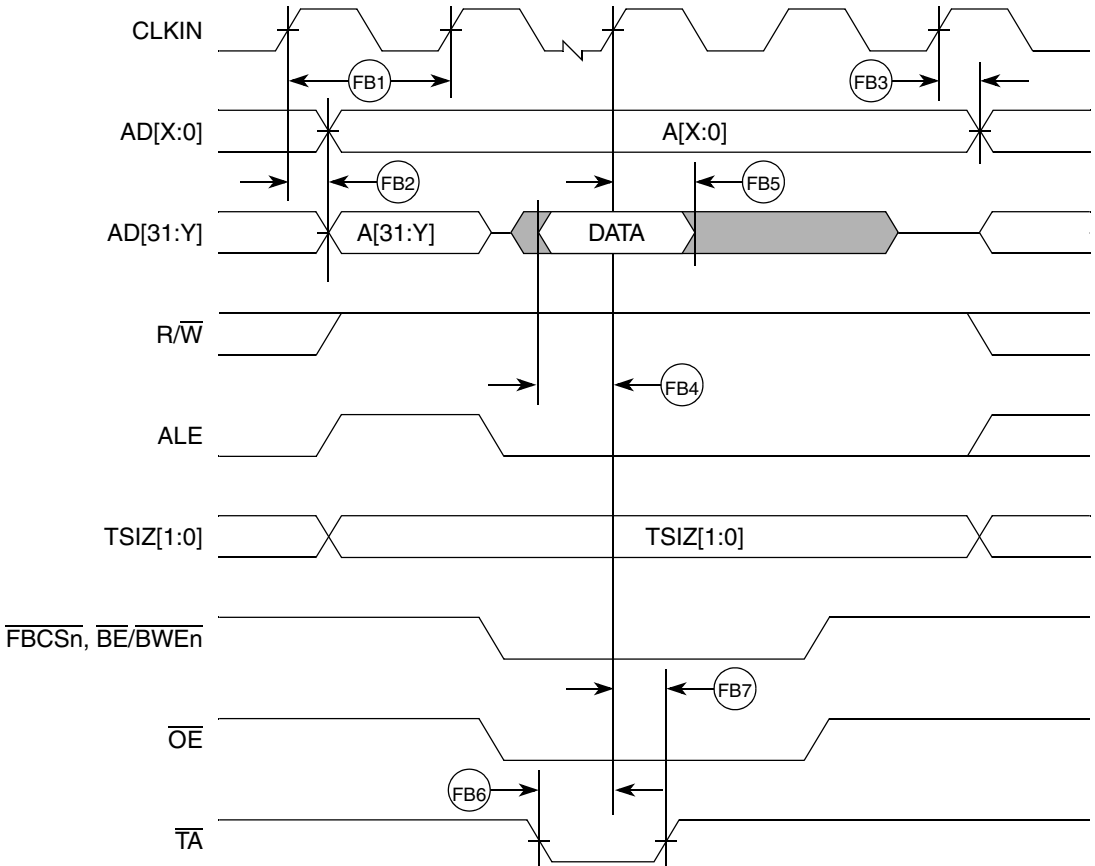


Figure 11. FlexBus Read Timing

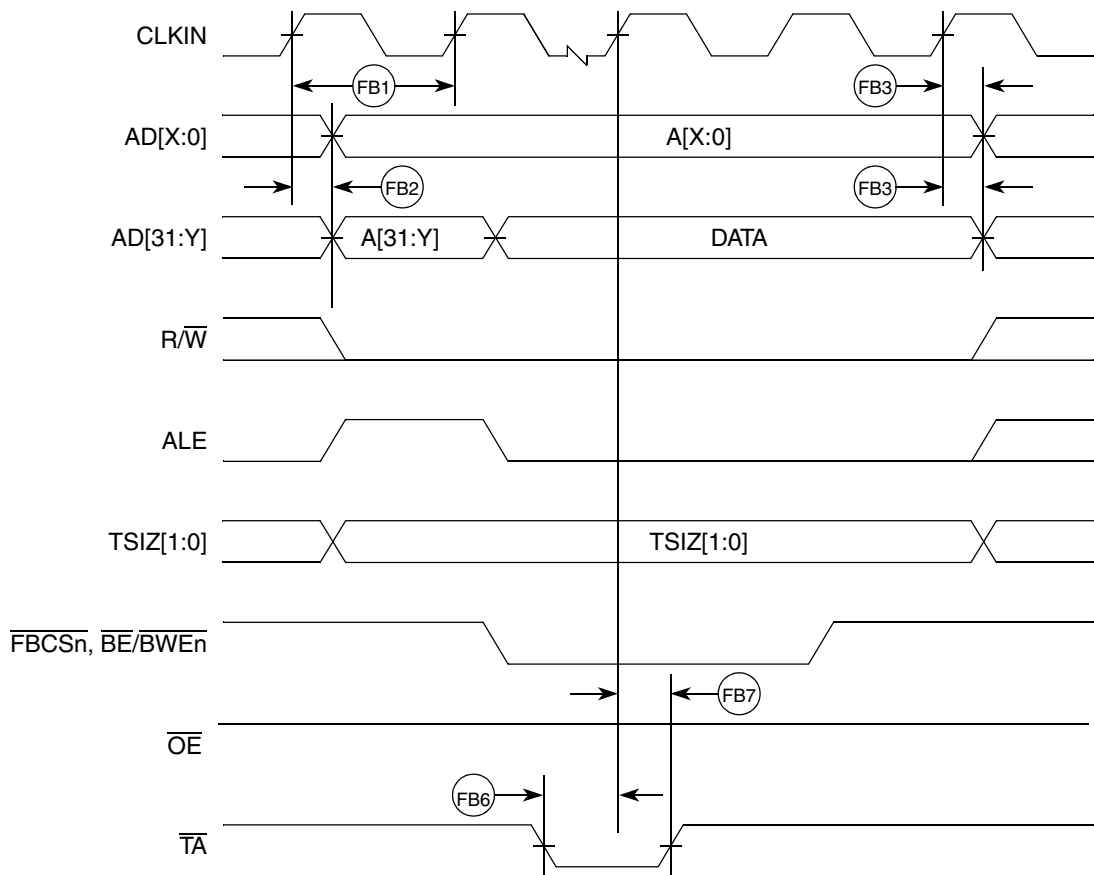


Figure 12. FlexBus Write Timing

9 SDRAM Bus

The SDRAM controller supports accesses to main SDRAM memory from any internal master. It supports standard SDRAM or double data rate (DDR) SDRAM, but it does not support both at the same time. The SDRAM controller uses SSTL2 and SSTL3 I/O drivers. Both SSTL drive modes are programmable for Class I or Class II drive strength.

9.1 SDR SDRAM AC Timing Characteristics

The following timing numbers indicate when data is latched or driven onto the external bus, relative to the memory bus clock, when operating in SDR mode on write cycles and relative to SDR_DQS on read cycles. The MCF548x SDRAM controller is a DDR controller that has an SDR mode. Because it is designed to support DDR, a DQS pulse must be supplied to the MCF548x for each data beat of an SDR read. The MCF548x accomplishes this by asserting a signal called SDR_DQS during read cycles. Care must be taken during board design to adhere to the following guidelines and specs with regard to the SDR_DQS signal and its usage.

Table 11. SDR Timing Specifications

Symbol	Characteristic	Min	Max	Unit	Notes
	Frequency of Operation	0	133	Mhz	1
SD1	Clock Period (t_{CK})	7.52	12	ns	2
SD2	Clock Skew (t_{SK})		TBD		
SD3	Pulse Width High (t_{CKH})	0.45	0.55	SDCLK	3
SD4	Pulse Width Low (t_{CKL})	0.45	0.55	SDCLK	4
SD5	Address, CKE, CAS, RAS, WE, BA, CS - Output Valid (t_{CMV})		$0.5 \times \text{SDCLK} + 1.0\text{ns}$	ns	
SD6	Address, CKE, CAS, RAS, WE, BA, CS - Output Hold (t_{CMH})	2.0		ns	
SD7	SDRDQS Output Valid (t_{DQSOV})		Self timed	ns	5
SD8	SDDQS[3:0] input setup relative to SDCLK ($t_{DQSI S}$)	$0.25 \times \text{SDCLK}$	$0.40 \times \text{SDCLK}$	ns	6
SD9	SDDQS[3:0] input hold relative to SDCLK (t_{DQSIH})	Does not apply. 0.5 SDCLK fixed width.			7
SD10	Data Input Setup relative to SDCLK (reference only) (t_{DIS})	$0.25 \times \text{SDCLK}$		ns	8
SD11	Data Input Hold relative to SDCLK (reference only) (t_{DIH})	1.0		ns	
SD12	Data and Data Mask Output Valid (t_{DV})		$0.75 \times \text{SDCLK} + 0.500\text{ns}$	ns	
SD13	Data and Data Mask Output Hold (t_{DH})	1.5		ns	

¹ The frequency of operation is 2x or 4x the CLKIN frequency of operation. The MCF548X supports a single external reference clock (CLKIN). This signal defines the frequency of operation for FlexBus and PCI, but SDRAM clock operates at the same frequency as the internal bus clock. Please see the PLL chapter of the *MCF548X Reference Manual* for more information on setting the SDRAM clock rate.

² SDCLK is one SDRAM clock in (ns).

³ Pulse width high plus pulse width low cannot exceed min and max clock period.

⁴ Pulse width high plus pulse width low cannot exceed min and max clock period.

⁵ SDR_DQS is designed to pulse 0.25 clock before the rising edge of the memory clock. This is a guideline only. Subtle variation from this guideline is expected. SDR_DQS only pulses during a read cycle and one pulse occurs for each data beat.

⁶ SDR_DQS is designed to pulse 0.25 clock before the rising edge of the memory clock. This spec is a guideline only. Subtle variation from this guideline is expected. SDR_DQS only pulses during a read cycle and one pulse occurs for each data beat.

⁷ The SDR_DQS pulse is designed to be 0.5 clock in width. The timing of the rising edge is most important. The falling edge does not affect the memory controller.

⁸ Because a read cycle in SDR mode uses the DQS circuit within the MCF548X, it is most critical that the data valid window be centered 1/4 clk after the rising edge of DQS. Ensuring that this happens results in successful SDR reads. The input setup spec is provided as guidance.

Table 13. DDR Timing Specifications (continued)

Symbol	Characteristic	Min	Max	Unit	Notes
DD13	DQS input read preamble width (t_{RPRE})	0.9	1.1	SDCLK	
DD14	DQS input read postamble width (t_{RPST})	0.4	0.6	SDCLK	
DD15	DQS output write preamble width (t_{WPRE})	0.25	—	SDCLK	
DD16	DQS output write postamble width (t_{WPST})	0.4	0.6	SDCLK	

¹ DDR memories typically have a minimum speed specification of 83 MHz. Check memory component specifications to verify.

² The frequency of operation is 2x or 4x the CLKIN frequency of operation. The MCF548X supports a single external reference clock (CLKIN). This signal defines the frequency of operation for FlexBus and PCI, but SDRAM clock operates at the same frequency as the internal bus clock. Please see the reset configuration signals description in the “Signal Descriptions” chapter within the *MCF548x Reference Manual*.

³ SDCLK is one memory clock in (ns).

⁴ Pulse width high plus pulse width low cannot exceed max clock period.

⁵ Pulse width high plus pulse width low cannot exceed max clock period.

⁶ Command output valid should be 1/2 the memory bus clock (SDCLK) plus some minor adjustments for process, temperature, and voltage variations.

⁷ This specification relates to the required input setup time of today's DDR memories. SDDATA[31:24] is relative to SDDQS3, SDDATA[23:16] is relative to SDDQS2, SDDATA[15:8] is relative to SDDQS1, and SDDATA[7:0] is relative SDDQS0.

⁸ The first data beat is valid before the first rising edge of SDDQS and after the SDDQS write preamble. The remaining data beats is valid for each subsequent SDDQS edge.

⁹ This specification relates to the required hold time of today's DDR memories. SDDATA[31:24] is relative to SDDQS3, SDDATA[23:16] is relative to SDDQS2, SDDATA[15:8] is relative to SDDQS1, and SDDATA[7:0] is relative SDDQS0.

¹⁰ Data input skew is derived from each SDDQS clock edge. It begins with a SDDQS transition and ends when the last data line becomes valid. This input skew must include DDR memory output skew and system level board skew (due to routing or other factors).

¹¹ Data input hold is derived from each SDDQS clock edge. It begins with a SDDQS transition and ends when the first data line becomes invalid.

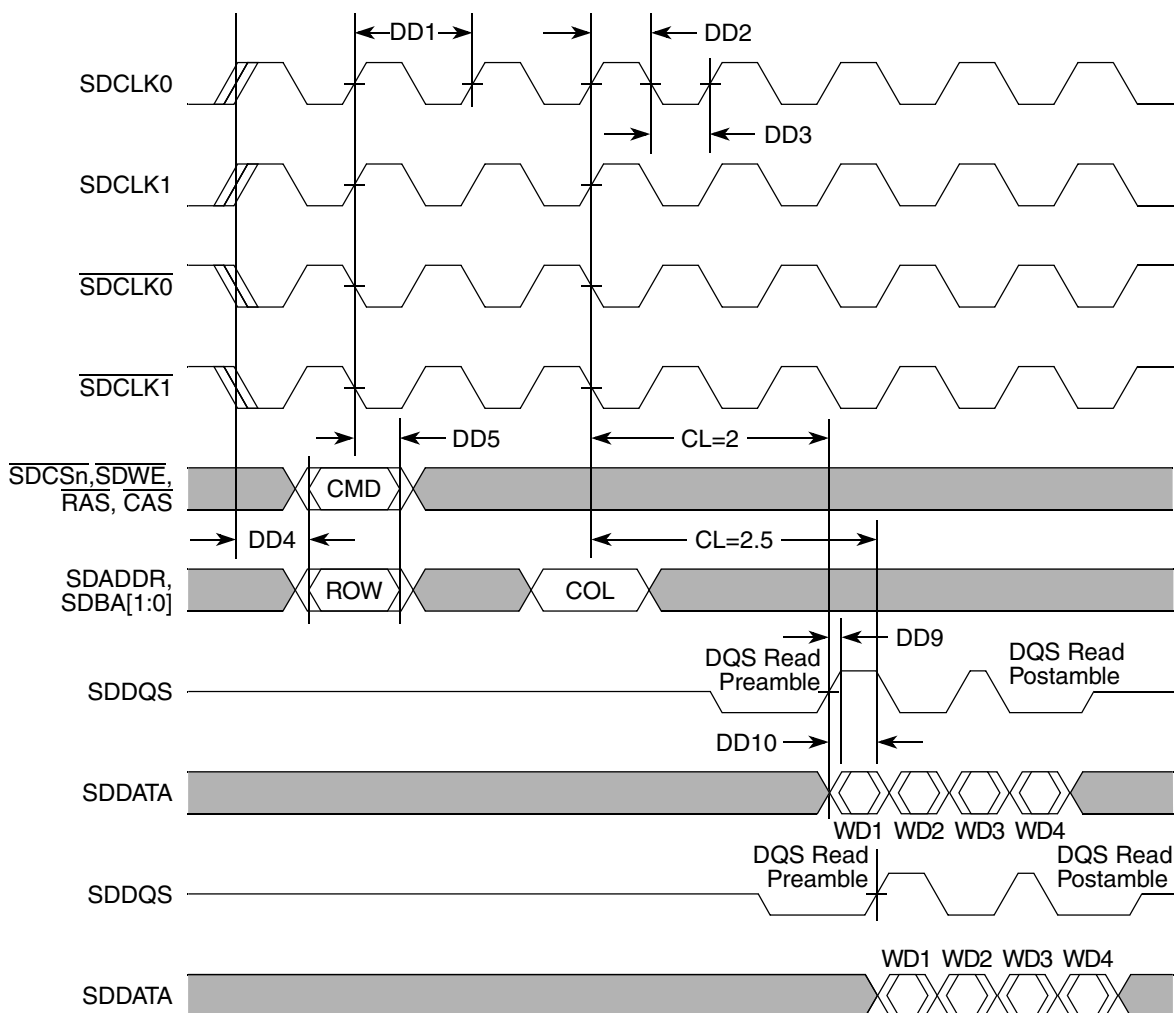


Figure 17. DDR Read Timing

10 PCI Bus

The PCI bus on the MCF548x is PCI 2.2 compliant. The following timing numbers are mostly from the PCI 2.2 spec. Please refer to the PCI 2.2 spec for a more detailed timing analysis.

Table 14. PCI Timing Specifications

Num	Characteristic	Min	Max	Unit	Notes
	Frequency of Operation	25	50	MHz	¹
P1	Clock Period (t_{CK})	20	40	ns	²
P2	Address, Data, and Command ($33 < \text{PCI} \leq 50 \text{ Mhz}$)—Input Setup (t_{IS})	3.0	—	ns	
P3	Address, Data, and Command ($0 < \text{PCI} \leq 33 \text{ Mhz}$)—Input Setup (t_{IS})	7.0	—	ns	
P4	Address, Data, and Command ($33\text{--}50 \text{ Mhz}$)—Output Valid (t_{DV})	—	6.0	ns	³
P5	Address, Data, and Command ($0\text{--}33 \text{ Mhz}$) - Output Valid (t_{DV})	—	11.0	ns	
P6	PCI signals ($0\text{--}50 \text{ Mhz}$) - Output Hold (t_{DH})	0	—	ns	⁴

Table 14. PCI Timing Specifications (continued)

Num	Characteristic	Min	Max	Unit	Notes
P7	PCI signals (0–50 Mhz) - Input Hold (t_{IH})	0	—	ns	⁵
P8	PCI REQ/GNT (33 < PCI ≤ 50Mhz) - Output valid (t_{DV})	—	6	ns	⁶
P9	PCI REQ/GNT (0 < PCI ≤ 33Mhz) - Output valid (t_{DV})	—	12	ns	
P10	PCI REQ/GNT (33 < PCI ≤ 50Mhz) - Input Setup (t_{IS})	—	5	ns	
P11	PCI REQ (0 < PCI ≤ 33Mhz) - Input Setup (t_{IS})	12	—	ns	
P12	PCI GNT (0 < PCI ≤ 33Mhz) - Input Setup (t_{IS})	10	—	ns	

- ¹ Please see the reset configuration signals description in the “Signal Descriptions” chapter within the *MCF548x Reference Manual*. Also specific guidelines may need to be followed when operating the system PLL below certain frequencies.
- ² Max cycle rate is determined by CLKIN and how the user has the system PLL configured.
- ³ All signals defined as PCI based signals. Does not include PTP (point-to-point) signals.
- ⁴ PCI 2.2 spec does not require an output hold time. Although the MCF548X may provide a slight amount of hold, it is not required or guaranteed.
- ⁵ PCI 2.2 spec requires zero input hold.
- ⁶ These signals are defined at PTP (Point-to-point) in the PCI 2.2 spec.

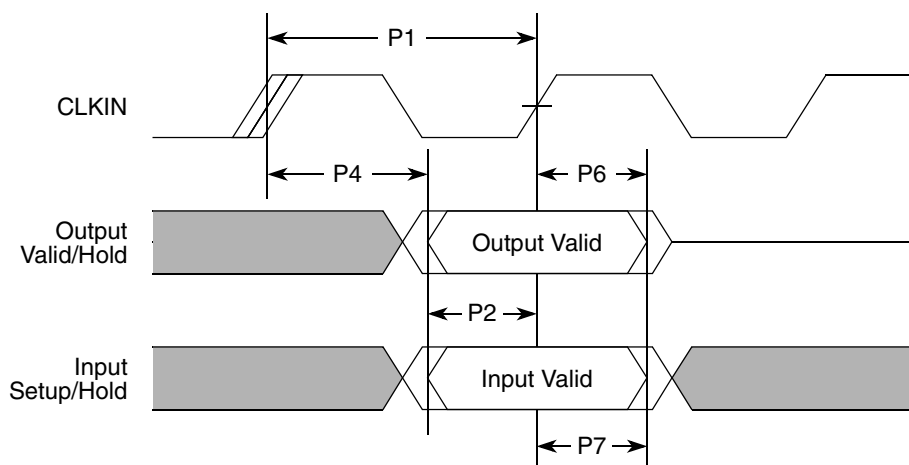


Figure 18. PCI Timing

11 Fast Ethernet AC Timing Specifications

11.1 MII/7-WIRE Interface Timing Specs

The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the EMAC_10_100 I/O signals.

The following timing specs meet the requirements for MII and 7-Wire style interfaces for a range of transceiver devices. If this interface is to be used with a specific transceiver device the timing specs may be altered to match that specific transceiver.

12 General Timing Specifications

Table 19 lists timing specifications for the GPIO, PSC, FlexCAN, $\overline{\text{DREQ}}$, $\overline{\text{DACK}}$, and external interrupts.

Table 19. General AC Timing Specifications

Name	Characteristic	Min	Max	Unit
G1	CLKIN high to signal output valid	—	2	PSTCLK
G2	CLKIN high to signal invalid (output hold)	0	—	ns
G3	Signal input pulse width	2	—	PSTCLK

13 I²C Input/Output Timing Specifications

Table 20 lists specifications for the I²C input timing parameters shown in Figure 23.

Table 20. I²C Input Timing Specifications between SCL and SDA

Num	Characteristic	Min	Max	Units
I1	Start condition hold time	2	—	Bus clocks
I2	Clock low period	8	—	Bus clocks
I3	SCL/SDA rise time ($V_{IL} = 0.5 \text{ V}$ to $V_{IH} = 2.4 \text{ V}$)	—	1	mS
I4	Data hold time	0	—	ns
I5	SCL/SDA fall time ($V_{IH} = 2.4 \text{ V}$ to $V_{IL} = 0.5 \text{ V}$)	—	1	mS
I6	Clock high time	4	—	Bus clocks
I7	Data setup time	0	—	ns
I8	Start condition setup time (for repeated start condition only)	2	—	Bus clocks
I9	Stop condition setup time	2	—	Bus clocks

Table 21 lists specifications for the I²C output timing parameters shown in Figure 23.

Table 21. I²C Output Timing Specifications between SCL and SDA

Num	Characteristic	Min	Max	Units
I1 ¹	Start condition hold time	6	—	Bus clocks
I2 ¹	Clock low period	10	—	Bus clocks
I3 ²	SCL/SDA rise time ($V_{IL} = 0.5 \text{ V}$ to $V_{IH} = 2.4 \text{ V}$)	—	—	μS
I4 ¹	Data hold time	7	—	Bus clocks
I5 ³	SCL/SDA fall time ($V_{IH} = 2.4 \text{ V}$ to $V_{IL} = 0.5 \text{ V}$)	—	3	ns
I6 ¹	Clock high time	10	—	Bus clocks
I7 ¹	Data setup time	2	—	Bus clocks
I8 ¹	Start condition setup time (for repeated start condition only)	20	—	Bus clocks
I9 ¹	Stop condition setup time	10	—	Bus clocks

15 DSPI Electrical Specifications

Table 24 lists DSPI timings.

Table 24. DSPI Modules AC Timing Specifications

Name	Characteristic	Min	Max	Unit
DS1	DSPI_CS[3:0] to DSPI_CLK	$1 \times t_{ck}$	$510 \times t_{ck}$	ns
DS2	DSPI_CLK high to DSPI_DOUT valid.	—	12	ns
DS3	DSPI_CLK high to DSPI_DOUT invalid. (Output hold)	2	—	ns
DS4	DSPI_DIN to DSPI_CLK (Input setup)	10	—	ns
DS5	DSPI_DIN to DSPI_CLK (Input hold)	10	—	ns

The values in Table 24 correspond to Figure 30.

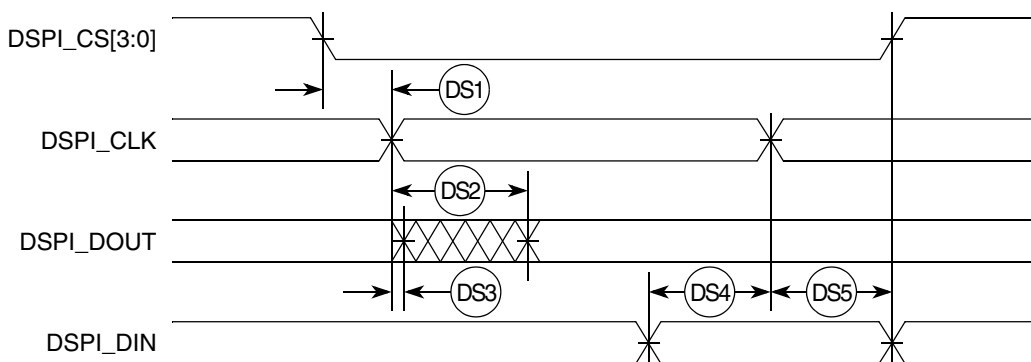


Figure 30. DSPI Timing

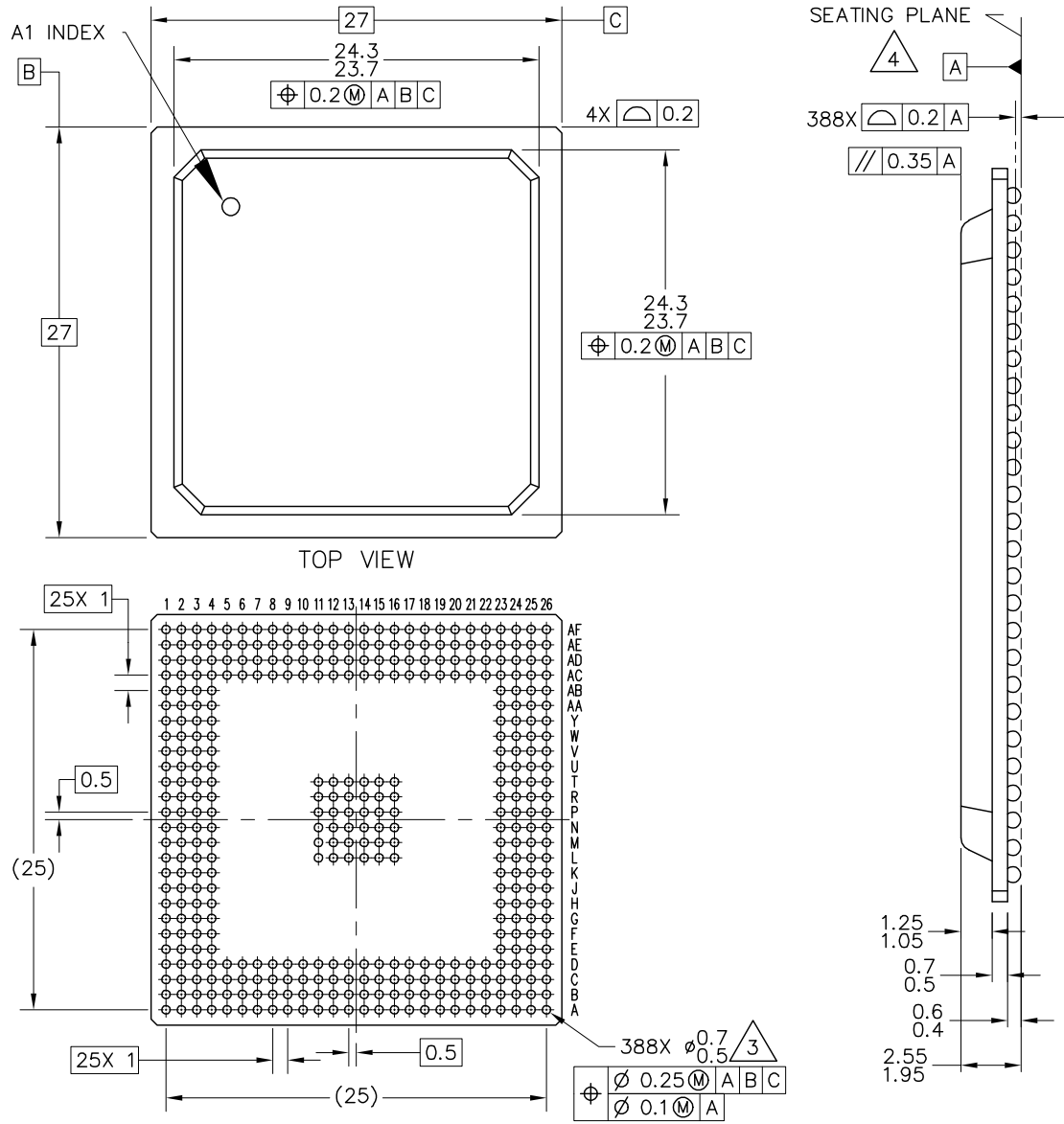
16 Timer Module AC Timing Specifications

Table 25 lists timer module AC timings.

Table 25. Timer Module AC Timing Specifications


Name	Characteristic	0–50 MHz		Unit
		Min	Max	
T1	TIN0 / TIN1 / TIN2 / TIN3 cycle time	3	—	PSTCLK
T2	TIN0 / TIN1 / TIN2 / TIN3 pulse width	1	—	PSTCLK

17 Case Drawing



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		CASE NUMBER: 1164-02		25 JAN 2007	
		STANDARD: JEDEC MS-034 AAL-1			

NOTES:

1. ALL DIMENSIONS IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.
4.  DATUM A, THE SEATING PLANE, IS DETERMINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.
5. PACKAGE CODES:
 5254 - 2 LAYER SUBSTRATE PACKAGE
 5367 - 4 LAYER SUBSTRATE PACKAGE

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	CASE NUMBER: 1164-02		25 JAN 2007
	STANDARD: JEDEC MS-034 AAL-1		

Figure 31. 388-pin BGA Case Outline

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